

2N6027  
2N6028

**SILICON  
PROGRAMMABLE  
UNIJUNCTION TRANSISTORS**



**TO-92 CASE**



[www.centralemi.com](http://www.centralemi.com)

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N6027 and 2N6028 devices are silicon programmable unijunction transistors, manufactured in an epoxy molded package, designed for adjustable (programmable) characteristics such as Valley Current ( $I_V$ ), Peak Current ( $I_P$ ), and Intrinsic Standoff Ratio ( $\eta$ ).

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Gate-Cathode Forward Voltage

Gate-Cathode Reverse Voltage

Gate-Anode Reverse Voltage

Anode-Cathode Voltage

Peak Non-Repetitive Forward Current ( $t=10\mu\text{s}$ )

Peak Repetitive Forward Current ( $t=20\mu\text{s}$ , D.C.=1.0%)

Peak Repetitive Forward Current ( $t=100\mu\text{s}$ , D.C.=1.0%)

DC Forward Anode Current

DC Gate Current

Power Dissipation

Operating Junction Temperature

Storage Temperature

**SYMBOL**

$V_{GKF}$  40

$V_{GKR}$  5.0

$V_{GAR}$  40

$V_{AK}$  40

$I_{TSM}$  5.0

$I_{TRM}$  2.0

$I_{TRM}$  1.0

$I_T$  150

$I_G$  50

$P_D$  300

$T_J$  -50 to +100

$T_{stg}$  -55 to +150

**UNITS**

V

V

V

V

A

A

A

mA

mA

mW

$^\circ\text{C}$

$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N6027		2N6028		UNITS
		MIN	MAX	MIN	MAX	
$I_{GAO}$	$V_S=40\text{V}$	-	10	-	10	nA
$I_{GKS}$	$V_S=40\text{V}$	-	50	-	50	nA
$I_P$	$V_S=10\text{V}$ , $R_G=1.0\text{M}\Omega$	-	2.0	-	0.15	$\mu\text{A}$
$I_P$	$V_S=10\text{V}$ , $R_G=10\text{k}\Omega$	-	5.0	-	1.0	$\mu\text{A}$
$I_V$	$V_S=10\text{V}$ , $R_G=1.0\text{M}\Omega$	-	50	-	25	$\mu\text{A}$
$I_V$	$V_S=10\text{V}$ , $R_G=10\text{k}\Omega$	70	-	25	-	$\mu\text{A}$
$I_V$	$V_S=10\text{V}$ , $R_G=200\Omega$	1.5	-	1.0	-	mA
$V_T$	$V_S=10\text{V}$ , $R_G=1.0\text{M}\Omega$	0.2	1.6	0.2	0.6	V
$V_T$	$V_S=10\text{V}$ , $R_G=10\text{k}\Omega$	0.2	0.6	0.2	0.6	V
$V_F$	$I_F=50\text{mA}$	-	1.5	-	1.5	V
$V_O$	$V_B=20\text{V}$ , $C_C=0.2\mu\text{F}$	6.0	-	6.0	-	V
$t_r$	$V_B=20\text{V}$ , $C_C=0.2\mu\text{F}$	-	80	-	80	ns

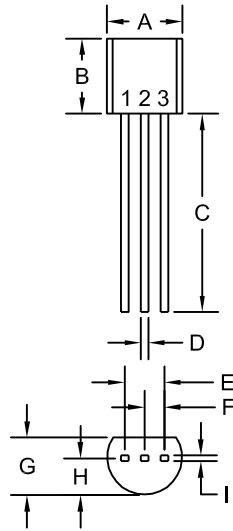
R2 (4-February 2014)

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#### TO-92 CASE - MECHANICAL OUTLINE



DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

#### LEAD CODE:

- 1) Anode
- 2) Gate
- 3) Cathode

**MARKING:**  
FULL PART NUMBER

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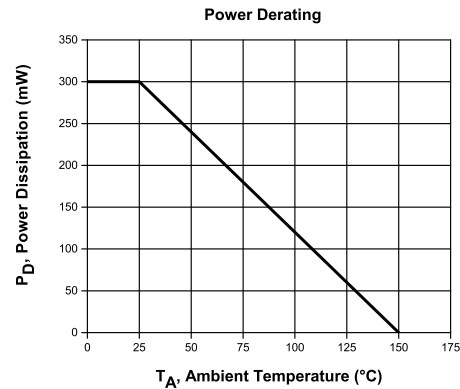
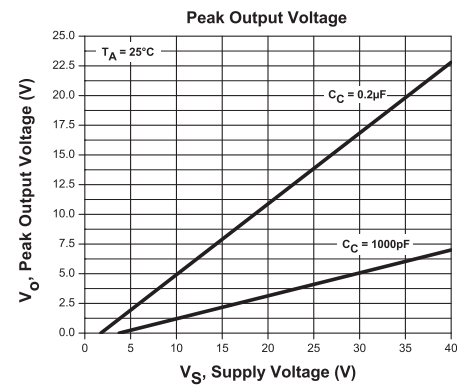
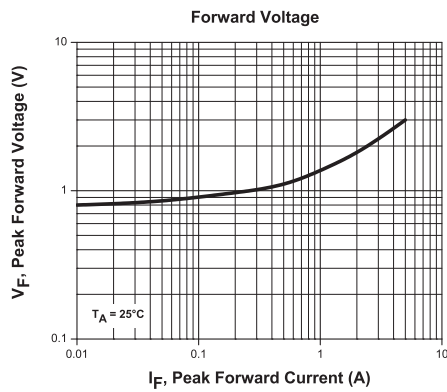
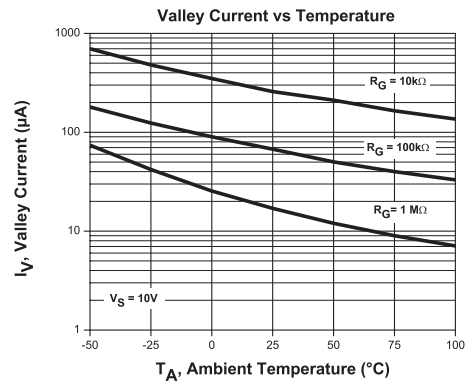
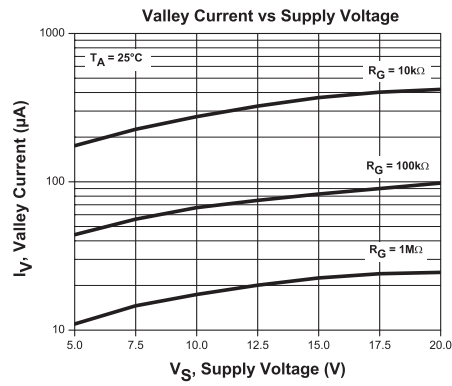
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TYPICAL ELECTRICAL CHARACTERISTICS



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## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

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